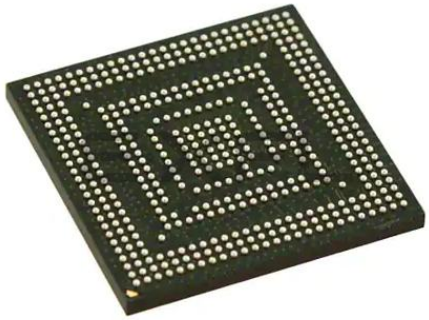


Welcome to E-XFL.COM

Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	ARM1136JF-S
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	532MHz
Co-Processors/DSP	Multimedia; GPU, IPU, MPEG-4, VFP
RAM Controllers	DDR
Graphics Acceleration	Yes
Display & Interface Controllers	Keyboard, Keypad, LCD
Ethernet	-
SATA	-
USB	USB 2.0 (3)
Voltage - I/O	1.8V, 2.0V, 2.5V, 2.7V, 3.0V
Operating Temperature	0°C ~ 70°C (TA)
Security Features	Random Number Generator, RTIC, Secure Fusebox, Secure JTAG, Secure Memory
Package / Case	457-LFBGA
Supplier Device Package	457-LFBGA (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx31lvkn5r2

1.2 Ordering Information

Table 1 provides the ordering information for the MCIMX31.

Table 1. Ordering Information

Part Number	Silicon Revision[1, 2, 3,4]	Device Mask	Operating Temperature Range (°C)	Package[5]
MCIMX31VKN5	1.15	2L38W and 3L38W	0 to 70	14 x 14 mm, 0.5 mm pitch, MAPBGA-457, Case 1581
MCIMX31LVKN5	1.15	2L38W and 3L38W	0 to 70	
MCIMX31VKN5B	1.2	M45G	0 to 70	
MCIMX31LVKN5B	1.2	M45G	0 to 70	
MCIMX31VKN5C	2.0	M91E	0 to 70	14 x 14 mm, 0.5 mm pitch, MAPBGA-457, Case 1581
MCIMX31LVKN5C	2.0	M91E	0 to 70	
MCIMX31CVKN5C	2.0	M91E	–40 to 85	
MCIMX31LCVKN5C	2.0	M91E	–40 to 85	
MCIMX31VMN5C	2.0	M91E	0 to 70	19 x 19 mm, 0.8 mm pitch, Case 1931
MCIMX31LVMN5C	2.0	M91E	0 to 70	

1 Information on reading the silicon revision register can be found in the IC Identification (IIM) chapter of the Reference Manual, see Section 7, "Product Documentation."

2 Errata and fix information of the various mask sets can be found in the standard MCIMX31 Chip Errata, see Section 7, "Product Documentation."

3 Changes in output buffer characteristics can be found in the I/O Setting Exceptions and Special Pad Descriptions table in the Reference Manual, see Section 7, "Product Documentation."

4 JTAG functionality is not tested nor guaranteed at -40°C.

5 Case 1581 and 1931 are RoHS compliant, lead-free, MSL = 3, and solders at 260°C.

1.2.1 Feature Differences Between Mask Sets

The following is a summary of differences between silicon Revision 2.0, mask set M91E, and previous revisions of silicon. A complete list of these differences is given in Table 72.

- Extended operating temperature range is available: –40°C to 85°C
- Supply current information changes, as shown in Table 13 and Table 14
- FUSE_VDD supply voltage is floated or grounded during read operation
- No restriction on PLL versus core supply voltage
- Operating frequency as shown in Table 8.

1.3 Block Diagram

Figure 1 shows the MCIMX31 simplified interface block diagram.

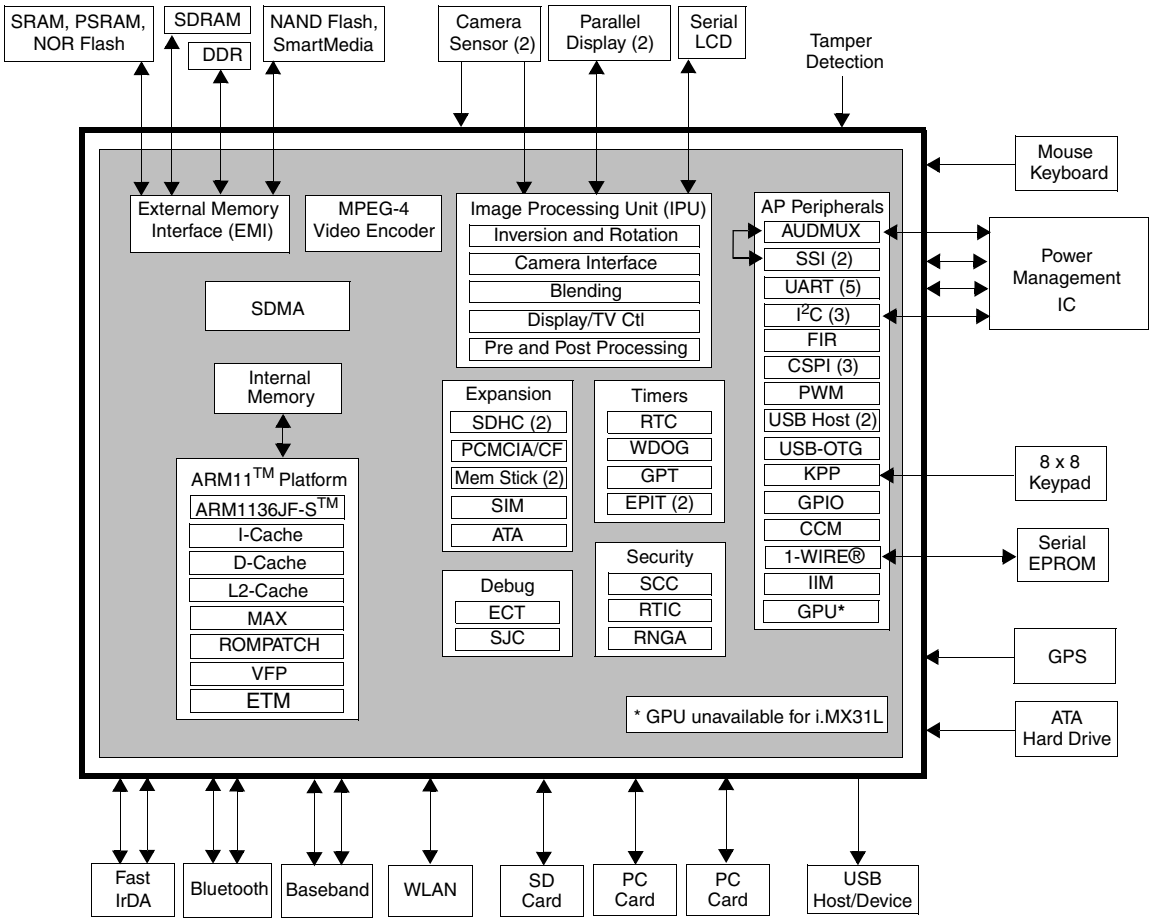


Figure 1. MCIMX31 Simplified Interface Block Diagram

2 Functional Description and Application Information

2.1 ARM11 Microprocessor Core

The CPU of the MCIMX31 is the ARM1136JF-S core based on the ARM v6 architecture. It supports the ARM Thumb® instruction sets, features Jazelle® technology (which enables direct execution of Java byte codes), and a range of SIMD DSP instructions that operate on 16-bit or 8-bit data values in 32-bit registers.

The ARM1136JF-S processor core features:

- Integer unit with integral EmbeddedICE™ logic
- Eight-stage pipeline
- Branch prediction with return stack
- Low-interrupt latency

2.2 Module Inventory

Table 3 shows an alphabetical listing of the modules in the multimedia applications processor. For extended descriptions of the modules, see the reference manual. A cross-reference is provided to the electrical specifications and timing information for each module with external signal connections.

Table 3. Digital and Analog Modules

Block Mnemonic	Block Name	Functional Grouping	Brief Description	Section/ Page
1-Wire®	1-Wire Interface	Connectivity Peripheral	The 1-Wire module provides bi-directional communication between the ARM11 core and external 1-Wire devices.	4.3.4/26
ATA	Advanced Technology (AT) Attachment	Connectivity Peripheral	The ATA block is an AT attachment host interface. It is designed to interface with IDE hard disc drives and ATAPI optical disc drives.	4.3.5/27
AUDMUX	Digital Audio Multiplexer	Multimedia Peripheral	The AUDMUX interconnections allow multiple, simultaneous audio/voice/data flows between the ports in point-to-point or point-to-multipoint configurations.	4.3.6/36
CAMP	Clock Amplifier Module	Clock	The CAMP converts a square wave/sinusoidal input into a rail-to-rail square wave. The output of CAMP feeds the predivider.	4.3.3/25
CCM	Clock Control Module	Clock	The CCM provides clock, reset, and power management control for the MCIMX31.	—
CSPI	Configurable Serial Peripheral Interface (x 3)	Connectivity Peripheral	The CSPI is equipped with data FIFOs and is a master/slave configurable serial peripheral interface module, capable of interfacing to both SPI master and slave devices.	4.3.7/36
DPLL	Digital Phase Lock Loop	Clock	The DPLLs produce high-frequency on-chip clocks with low frequency and phase jitters. **Note:** External clock sources provide the reference frequencies.	4.3.8/37
ECT	Embedded Cross Trigger	Debug	The ECT is composed of three CTIs (Cross Trigger Interface) and one CTM (Cross Trigger Matrix—key in the multi-core and multi-peripheral debug strategy.	—
EMI	External Memory Interface	Memory Interface (EMI)	The EMI includes • Multi-Master Memory Interface (M3IF) • Enhanced SDRAM Controller (ESDCTL) • NAND Flash Controller (NFC) • Wireless External Interface Module (WEIM)	— 4.3.9.3/46, 4.3.9.1/38, 4.3.9.2/41
EPIT	Enhanced Periodic Interrupt Timer	Timer Peripheral	The EPIT is a 32-bit “set and forget” timer which starts counting after the EPIT is enabled by software. It is capable of providing precise interrupts at regular intervals with minimal processor intervention.	—
ETM	Embedded Trace Macrocell	Debug/Trace	The ETM (from ARM, Ltd.) supports real-time instruction and data tracing by way of ETM auxiliary I/O port.	4.3.10/54
FIR	Fast InfraRed Interface	Connectivity Peripheral	This FIR is capable of establishing a 0.576 Mbit/s, 1.152 Mbit/s or 4 Mbit/s half duplex link via a LED and IR detector. It supports 0.576 Mbit/s, 1.152 Mbit/s medium infrared (MIR) physical layer protocol and 4Mbit/s fast infrared (FIR) physical layer protocol defined by IrDA, Rev. 1.4.	4.3.11/55

4 Electrical Characteristics

This section provides the device-level and module-level electrical characteristics for the MCIMX31.

4.1 Chip-Level Conditions

This section provides the device-level electrical characteristics for the IC. See Table 4 for a quick reference to the individual tables and sections.

Table 4. MCIMX31 Chip-Level Conditions

For these characteristics, …	Topic appears …
Table 5, “Absolute Maximum Ratings”	on page 10
Table 7, “Thermal Resistance Data—19 × 19 mm Package”	on page 11
Table 8, “Operating Ranges”	on page 13
Table 9, “Specific Operating Ranges for Silicon Revision 2.0”	on page 14
Table 10, “Interface Frequency”	on page 14
Section 4.1.1, “Supply Current Specifications”	on page 16
Section 4.2, “Supply Power-Up/Power-Down Requirements and Restrictions”	on page 19

CAUTION

Stresses beyond those listed under Table 5 may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under Table 8, "Operating Ranges," on page 13 is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 5. Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Units
Supply Voltage (Core)	$QVCC_{max}$	–0.5	1.65	V
Supply Voltage (I/O)	$NVCC_{max}$	–0.5	3.3	V
Input Voltage Range	V_{Imax}	–0.5	NVCC +0.3	V
Storage Temperature	$T_{storage}$	–40	125	°C
ESD Damage Immunity:				
Human Body Model (HBM)	V_{esd}	—	1500	V
Machine Model (MM)		—	200	
Charge Device Model (CDM)		—	500	
Offset voltage allowed in run mode between core supplies.	V_{core_offset} [1]	—	15	mV

[1] The offset is the difference between all core voltage pair combinations of QVCC, QVCC1, and QVCC4.

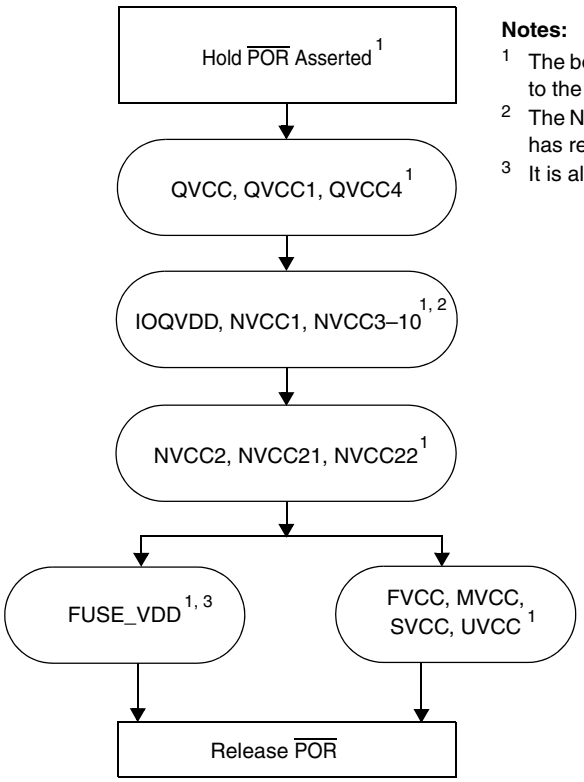
Table 14 shows the core current consumption for 0°C to 70°C for Silicon Revision 2.0 for the MCIMX31.

Table 14. Current Consumption for 0°C to 70°C[1, 2] for Silicon Revision 2.0

Mode	Conditions	QVCC (Peripheral)		QVCC1 (ARM)		QVCC4 (L2)		FVCC, +MVCC, +SVCC, +UVCC (PLL)		Unit
		Typ	Max	Typ	Max	Typ	Max	Typ	Max	
Deep Sleep	• QVCC = 0.95 V • ARM and L2 caches are power gated (QVCC1 2= QVCC4 = 0 V) • All PLLs are off, VCC = 1.4 V • ARM is in well bias • FPM is off • 32 kHz input is on • CKIH input is off • CAMP is off • TCK input is off • All modules are off • No external resistive loads • RNGA oscillator is off	0.16	2.50	—	—	—	—	0.02	0.10	mA
State Retention	• QVCC and QVCC1 = 0.95 V • L2 caches are power gated (QVCC4 = 0 V) • All PLLs are off, VCC = 1.4 V • ARM is in well bias • FPM is off • 32 kHz input is on • CKIH input is off • CAMP is off • TCK input is off • All modules are off • No external resistive loads • RNGA oscillator is off	0.16	2.50	0.07	1.60	—	—	0.02	0.10	mA
Wait	• QVCC, QVCC1, and QVCC4 = 1.22 V • ARM is in wait for interrupt mode • MAX is active • L2 cache is stopped but powered • MCU PLL is on (532 MHz), VCC = 1.4 V • USB PLL and SPLL are off, VCC = 1.4 V • FPM is on • CKIH input is on • CAMP is on • 32 kHz input is on • All clocks are gated off • All modules are off (by programming CGR[2:0] registers) • RNGA oscillator is off • No external resistive loads	6.00	13.00	2.20	16.00	0.03	0.17	3.60	4.40	mA

1 Typical column: TA = 25°C

2 Maximum column: TA = 70°C



Notes:

1. The board design must guarantee that supplies reach 90% level before transition to the next state, using Power Management IC or other means.
2. The NVCC1 supply must not precede IOQVDD by more than 0.2 V until IOQVDD has reached 1.5 V. If IOQVDD is powered up first, there are no restrictions.
3. It is allowable for FVCC, MVCC, SVCC, and UVCC to be up after FUSE_VDD.

Figure 2. Power-Up Sequence for Silicon Revisions 1.2 and Previous

4.2.1.1 Power-Up Sequence for Silicon Revision 2

Silicon revision 2.0 offers two options for power-up sequencing. Option 1 is backwards compatible with silicon revision 1.2 and earlier versions of the IC. It should be noted that using option 1 on silicon Rev. 2.0 introduces a slight increase in current drain on IOQVDD when IOQVDD is raised before NVCC21. The expected resulting increase is in the range of 3 mA to 5 mA, which does not pose a risk to the IC.

Option 2 is an alternative power-up sequence that allows the powering up of NVCC2, NVCC21, NVCC22 with IOQVDD, NVCC1, and NVCC3-10 without producing a current drain increase on IOQVDD.

These two power-up options on the 2.0 silicon allow the user to select the optimum power-up sequence for their application.

4.3.4 1-Wire Electrical Specifications

Figure 7 depicts the RPP timing, and Table 21 lists the RPP timing parameters.

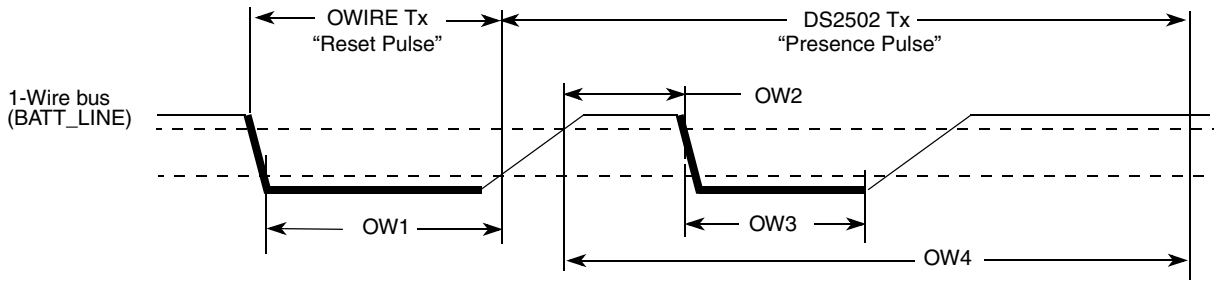


Figure 7. Reset and Presence Pulses (RPP) Timing Diagram

Table 21. RPP Sequence Delay Comparisons Timing Parameters

ID	Parameters	Symbol	Min	Typ	Max	Units
OW1	Reset Time Low	t_{RSTL}	480	511	—	µs
OW2	Presence Detect High	t_{PDH}	15	—	60	µs
OW3	Presence Detect Low	t_{PDL}	60	—	240	µs
OW4	Reset Time High	t_{RSTH}	480	512	—	µs

Figure 8 depicts Write 0 Sequence timing, and Table 22 lists the timing parameters.

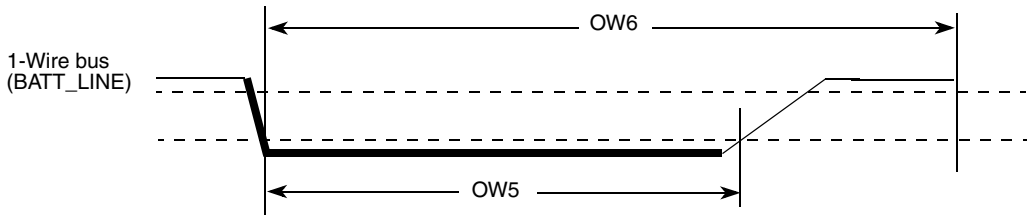


Figure 8. Write 0 Sequence Timing Diagram

Table 22. WR0 Sequence Timing Parameters

ID	Parameter	Symbol	Min	Typ	Max	Units
OW5	Write 0 Low Time	t_{WR0_low}	60	100	120	µs
OW6	Transmission Time Slot	t_{SLOT}	OW5	117	120	µs

Figure 9 depicts Write 1 Sequence timing, Figure 10 depicts the Read Sequence timing, and Table 23 lists the timing parameters.

4.3.5.1 Timing Parameters

In the timing equations, some timing parameters are used. These parameters depend on the implementation of the ATA interface on silicon, the bus buffer used, the cable delay and cable skew. Table 24 shows ATA timing parameters.

Table 24. ATA Timing Parameters

Name	Description	Value/ Contributing Factor[1]
T	Bus clock period (ipg_clk_ata)	peripheral clock frequency
ti_ds	Set-up time ata_data to ata_iordy edge (UDMA-in only) UDMA0 UDMA1 UDMA2, UDMA3 UDMA4 UDMA5	 15 ns 10 ns 7 ns 5 ns 4 ns
ti_dh	Hold time ata_iordy edge to ata_data (UDMA-in only) UDMA0, UDMA1, UDMA2, UDMA3, UDMA4 UDMA5	 5.0 ns 4.6 ns
tco	Propagation delay bus clock L-to-H to ata_cs0, ata_cs1, ata_da2, ata_da1, ata_da0, ata_dior, ata_diow, ata_dmack, ata_data, ata_buffer_en	12.0 ns
tsu	Set-up time ata_data to bus clock L-to-H	8.5 ns
tsui	Set-up time ata_iordy to bus clock H-to-L	8.5 ns
thi	Hold time ata_iordy to bus clock H to L	2.5 ns
tskew1	Max difference in propagation delay bus clock L-to-H to any of following signals ata_cs0, ata_cs1, ata_da2, ata_da1, ata_da0, ata_dior, ata_diow, ata_dmack, ata_data (write), ata_buffer_en	7 ns
tskew2	Max difference in buffer propagation delay for any of following signals ata_cs0, ata_cs1, ata_da2, ata_da1, ata_da0, ata_dior, ata_diow, ata_dmack, ata_data (write), ata_buffer_en	transceiver
tskew3	Max difference in buffer propagation delay for any of following signals ata_iordy, ata_data (read)	transceiver
tbuf	Max buffer propagation delay	transceiver
tcable1	Cable propagation delay for ata_data	cable
tcable2	Cable propagation delay for control signals ata_dior, ata_diow, ata_iordy, ata_dmack	cable
tskew4	Max difference in cable propagation delay between ata_iordy and ata_data (read)	cable
tskew5	Max difference in cable propagation delay between (ata_dior, ata_diow, ata_dmack) and ata_cs0, ata_cs1, ata_da2, ata_da1, ata_da0, ata_data(write)	cable
tskew6	Max difference in cable propagation delay without accounting for ground bounce	cable

[1] Values provided where applicable.

Table 31. DPLL Specifications (continued)

Parameter	Min	Typ	Max	Unit	Comments
Phase lock time	—	—	100	µs	In addition to the frequency
Maximum allowed PLL supply voltage ripple	—	—	25	mV	$F_{modulation}$ < 50 kHz
Maximum allowed PLL supply voltage ripple	—	—	20	mV	50 kHz < $F_{modulation}$ < 300 kHz
Maximum allowed PLL supply voltage ripple	—	—	25	mV	$F_{modulation}$ > 300 kHz
PLL output clock phase jitter	—	—	5.2	ns	Measured on CLKO pin
PLL output clock period jitter	—	—	420	ps	Measured on CLKO pin

1 The user or board designer must take into account that the use of a frequency other than 26 MHz would require adjustment to the DPTC–DVFS table, which is incorporated into operating system code.

2 The PLL reference frequency must be ≤ 35 MHz. Therefore, for frequencies between 35 MHz and 70 MHz, program the predivider to divide by 2 or more. If the CKIH frequency is above 70 MHz, program the predivider to 3 or more. For PD bit description, see the reference manual.

4.3.9 EMI Electrical Specifications

This section provides electrical parametrics and timings for EMI module.

4.3.9.1 NAND Flash Controller Interface (NFC)

The NFC supports normal timing mode, using two flash clock cycles for one access of $\overline{RE}$ and $\overline{WE}$. AC timings are provided as multiplications of the clock cycle and fixed delay. Figure 23, Figure 24, Figure 25, and Figure 26 depict the relative timing requirements among different signals of the NFC at module level, for normal mode, and Table 32 lists the timing parameters.

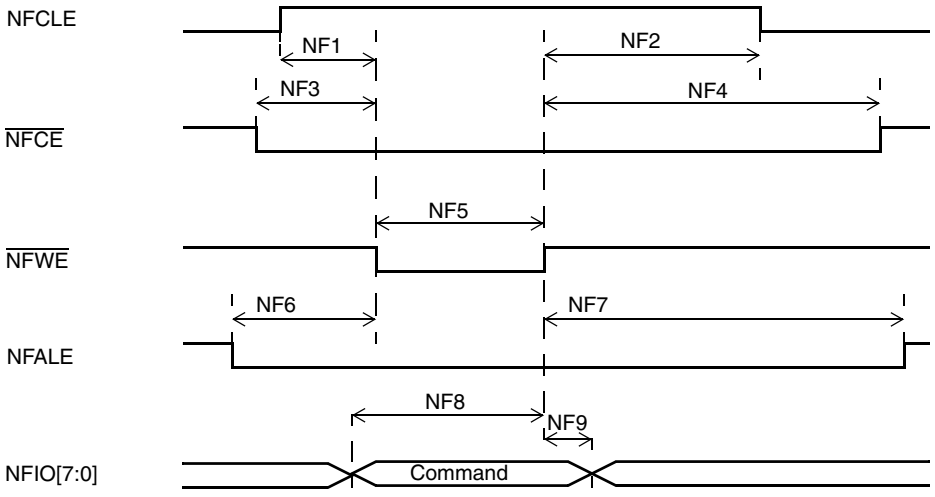


Figure 23. Command Latch Cycle Timing Diagram

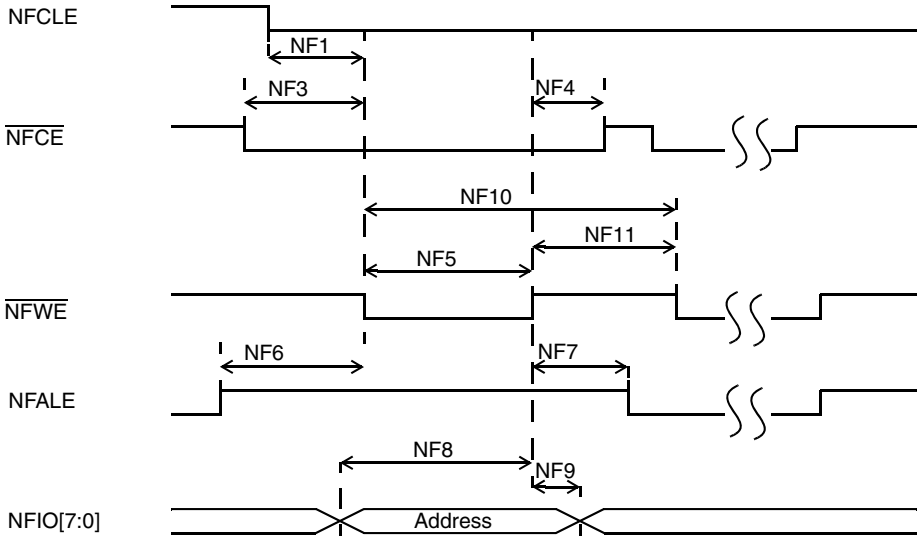


Figure 24. Address Latch Cycle Timing Diagram

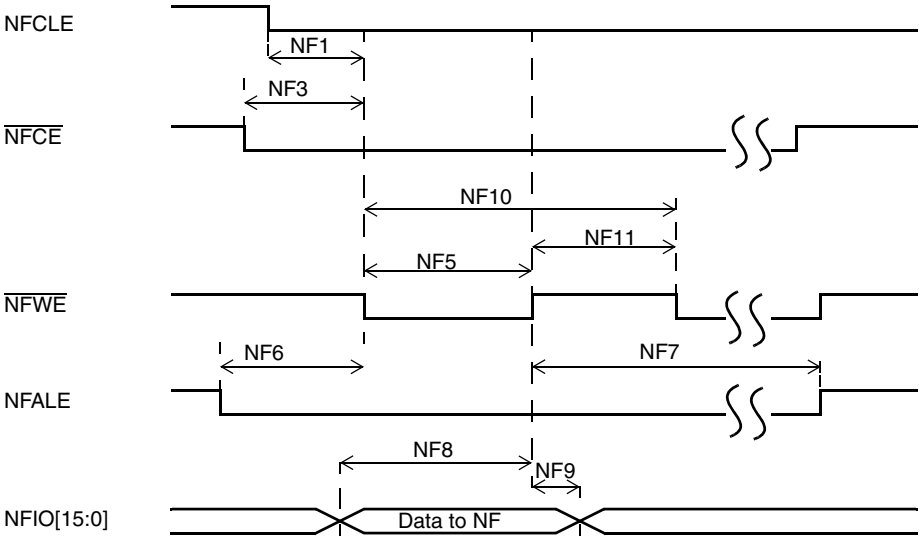


Figure 25. Write Data Latch Cycle Timing Diagram

Table 35. SDR SDRAM Write Timing Parameters (continued)

ID	Parameter	Symbol	Min	Max	Unit
SD13	Data setup time	tDS	2.0	—	ns
SD14	Data hold time	tDH	1.3	—	ns

[1] SD11 and SD12 are determined by SDRAM controller register settings.

NOTE

SDR SDRAM CLK parameters are being measured from the 50% point—that is, high is defined as 50% of signal value and low is defined as 50% of signal value.

The timing parameters are similar to the ones used in SDRAM data sheets—that is, Table 35 indicates SDRAM requirements. All output signals are driven by the ESDCTL at the negative edge of SDCLK and the parameters are measured at maximum memory frequency.

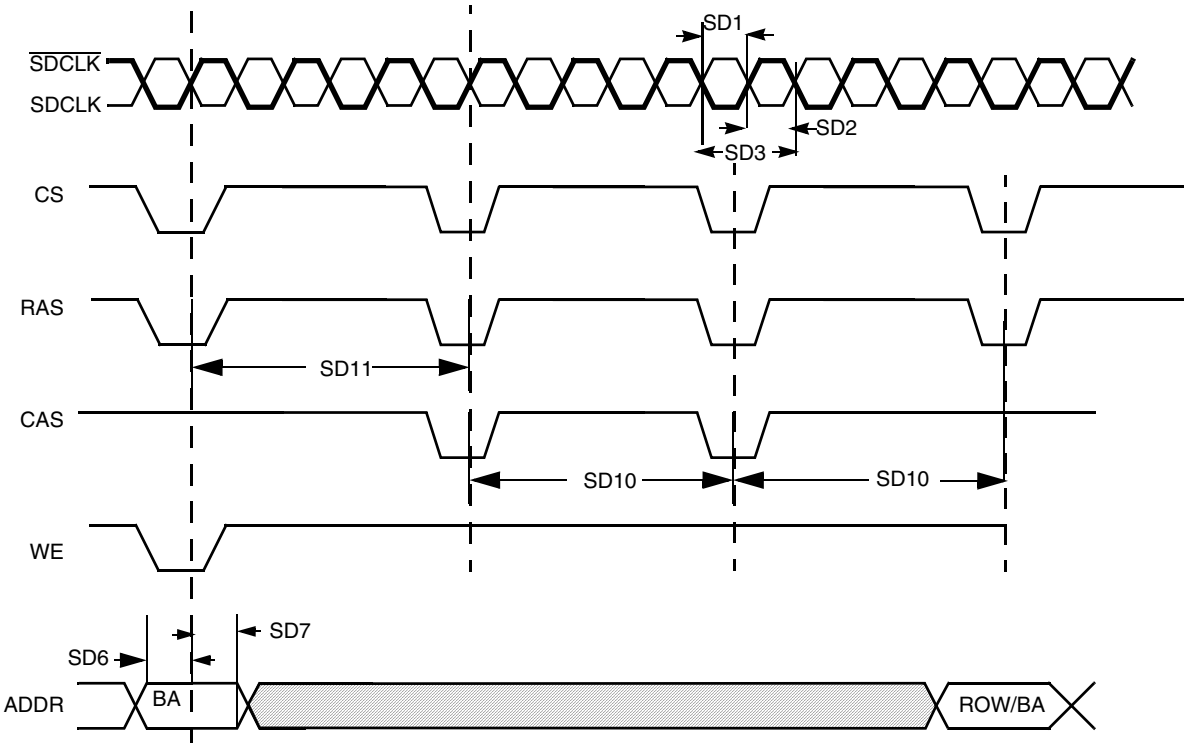


Figure 36. SDRAM Refresh Timing Diagram

Table 36. SDRAM Refresh Timing Parameters

ID	Parameter	Symbol	Min	Max	Unit
SD1	SDRAM clock high-level width	tCH	3.4	4.1	ns
SD2	SDRAM clock low-level width	tCL	3.4	4.1	ns

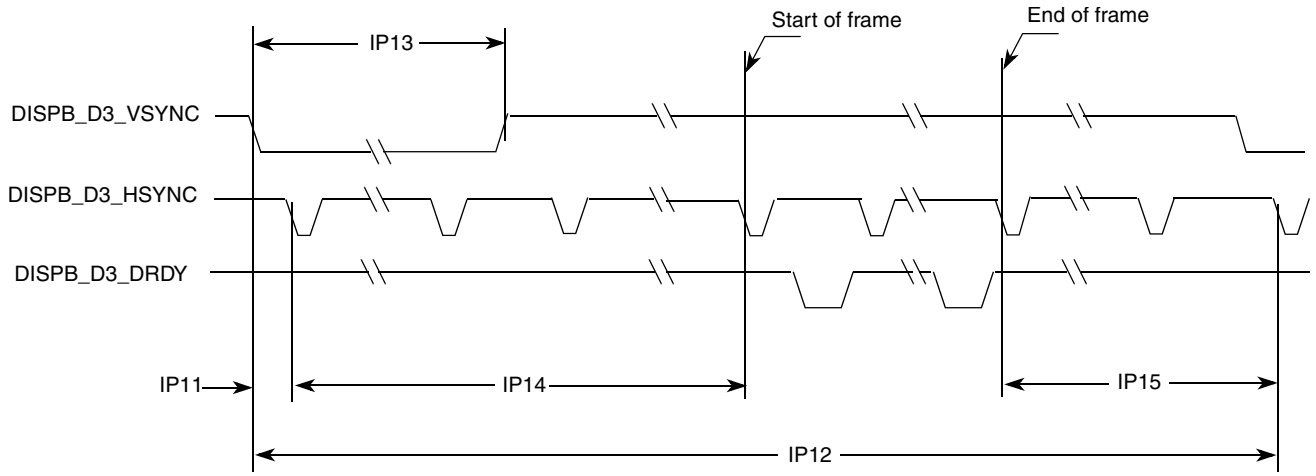


Figure 48. TFT Panels Timing Diagram—Vertical Sync Pulse

Table 47 shows timing parameters of signals presented in Figure 47 and Figure 48.

Table 47. Synchronous Display Interface Timing Parameters—Pixel Level

ID	Parameter	Symbol	Value	Units
IP5	Display interface clock period	Tdicp	Tdicp[1]	ns
IP6	Display pixel clock period	Tdpcp	(DISP3_IF_CLK_CNT_D+1) * Tdicp	ns
IP7	Screen width	Tsw	(SCREEN_WIDTH+1) * Tdpcp	ns
IP8	HSYNC width	Thsw	(H_SYNC_WIDTH+1) * Tdpcp	ns
IP9	Horizontal blank interval 1	Thbi1	BGXP * Tdpcp	ns
IP10	Horizontal blank interval 2	Thbi2	(SCREEN_WIDTH – BGXP – FW) * Tdpcp	ns
IP11	HSYNC delay	Thsd	H_SYNC_DELAY * Tdpcp	ns
IP12	Screen height	Tsh	(SCREEN_HEIGHT+1) * Tsw	ns
IP13	VSYNC width	Tvsw	if V_SYNC_WIDTH_L = 0 than (V_SYNC_WIDTH+1) * Tdpcp else (V_SYNC_WIDTH+1) * Tsw	ns
IP14	Vertical blank interval 1	Tvbi1	BGYP * Tsw	ns
IP15	Vertical blank interval 2	Tvbi2	(SCREEN_HEIGHT – BGYP – FH) * Tsw	ns

[1] Display interface clock period immediate value.

$$Tdicp = \begin{cases} T_{HSP\_CLK} \cdot \frac{DISP3\_IF\_CLK\_PER\_WR}{HSP\_CLK\_PERIOD}, & \text{for integer } \frac{DISP3\_IF\_CLK\_PER\_WR}{HSP\_CLK\_PERIOD} \\ T_{HSP\_CLK} \cdot \left(\text{floor}\left[\frac{DISP3\_IF\_CLK\_PER\_WR}{HSP\_CLK\_PERIOD} \right] + 0.5 \pm 0.5 \right), & \text{for fractional } \frac{DISP3\_IF\_CLK\_PER\_WR}{HSP\_CLK\_PERIOD} \end{cases}$$

Display interface clock period average value.

$$\overline{T}dicp = T_{HSP\_CLK} \cdot \frac{DISP3\_IF\_CLK\_PER\_WR}{HSP\_CLK\_PERIOD}$$

2 Display interface clock down time

$$Tdicd = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP3\_IF\_CLK\_DOWN\_WR}{HSP\_CLK\_PERIOD}\right]$$

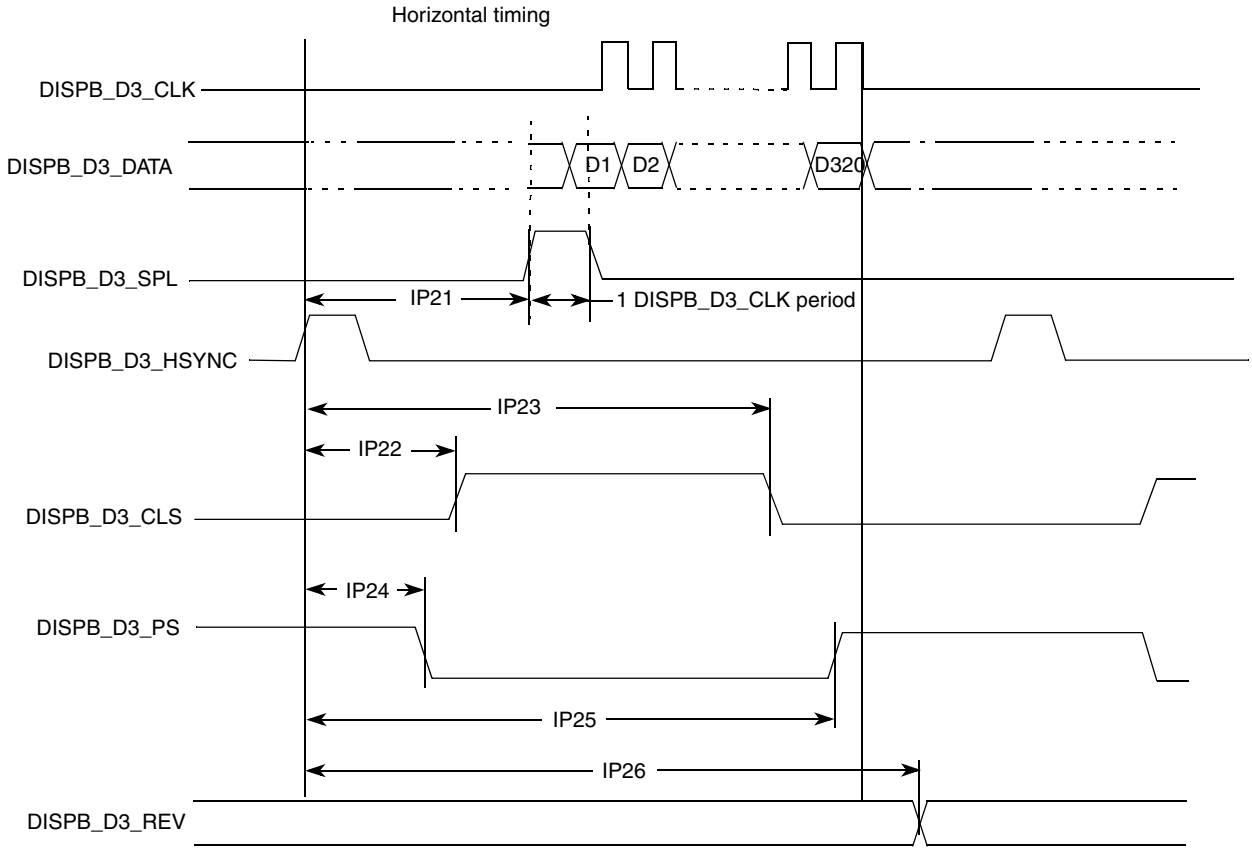
3 Display interface clock up time

$$Tdicu = \frac{1}{2}T_{HSP\_CLK} \cdot ceil\left[\frac{2 \cdot DISP3\_IF\_CLK\_UP\_WR}{HSP\_CLK\_PERIOD}\right]$$

where CEIL(X) rounds the elements of X to the nearest integers towards infinity.

4.3.15.3 Interface to Sharp HR-TFT Panels

Figure 50 depicts the Sharp HR-TFT panel interface timing, and Table 49 lists the timing parameters. The CLS_RISE_DELAY, CLS_FALL_DELAY, PS_FALL_DELAY, PS_RISE_DELAY, REV_TOGGLE_DELAY parameters are defined in the SDC_SHARP_CONF_1 and SDC_SHARP_CONF_2 registers. For other Sharp interface timing characteristics, refer to Section 4.3.15.2.2, "Interface to Active Matrix TFT LCD Panels, Electrical Characteristics." The timing images correspond to straight polarity of the Sharp signals.



Example is drawn with FW+1=320 pixel/line, FH+1=240 lines.
SPL pulse width is fixed and aligned to the first data of the line.
REV toggles every HSYNC period.

Figure 50. Sharp HR-TFT Panel Interface Timing Diagram—Pixel Level

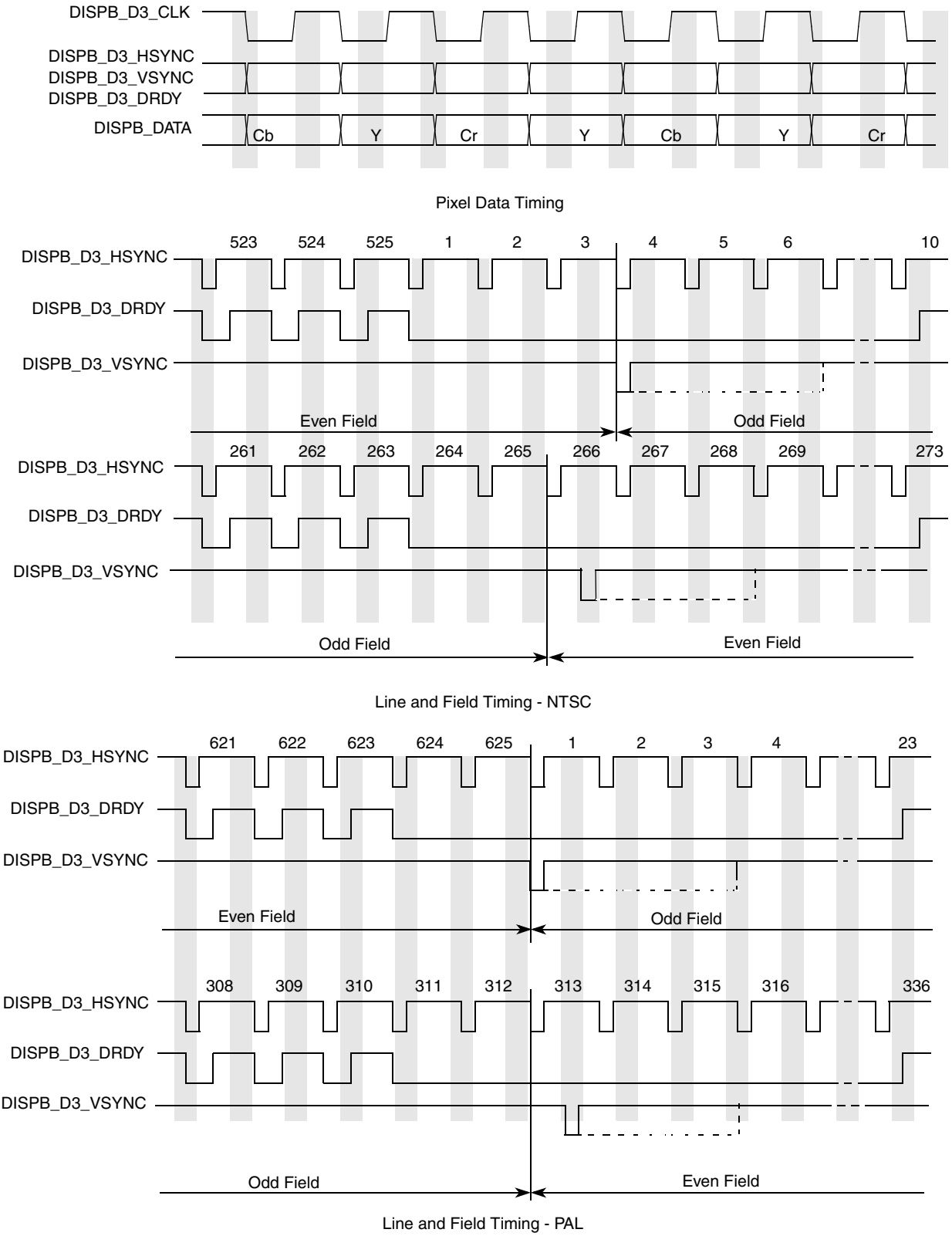


Figure 51. TV Encoder Interface Timing Diagram

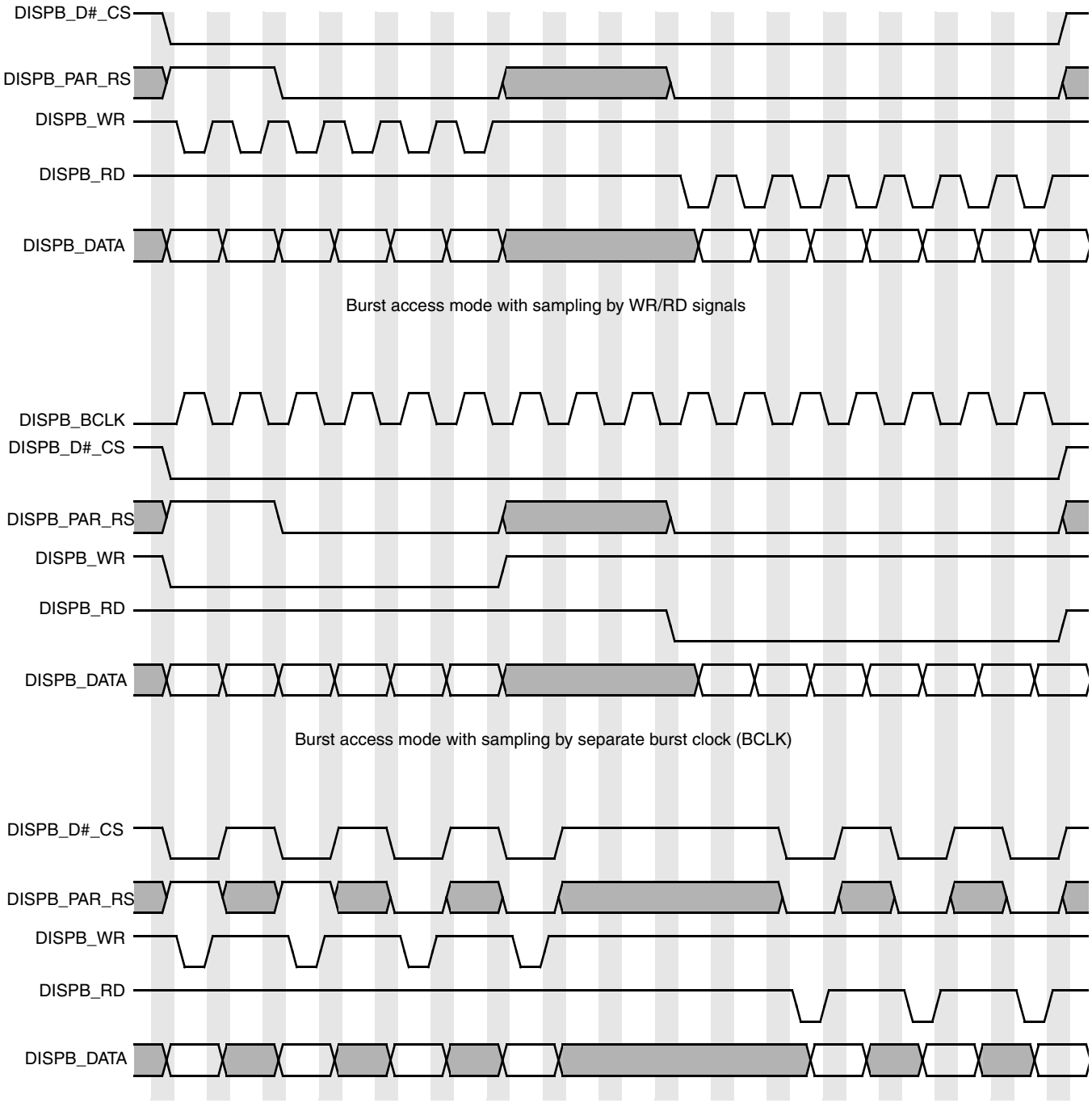


Figure 53. Asynchronous Parallel System 80 Interface (Type 2) Burst Mode Timing Diagram

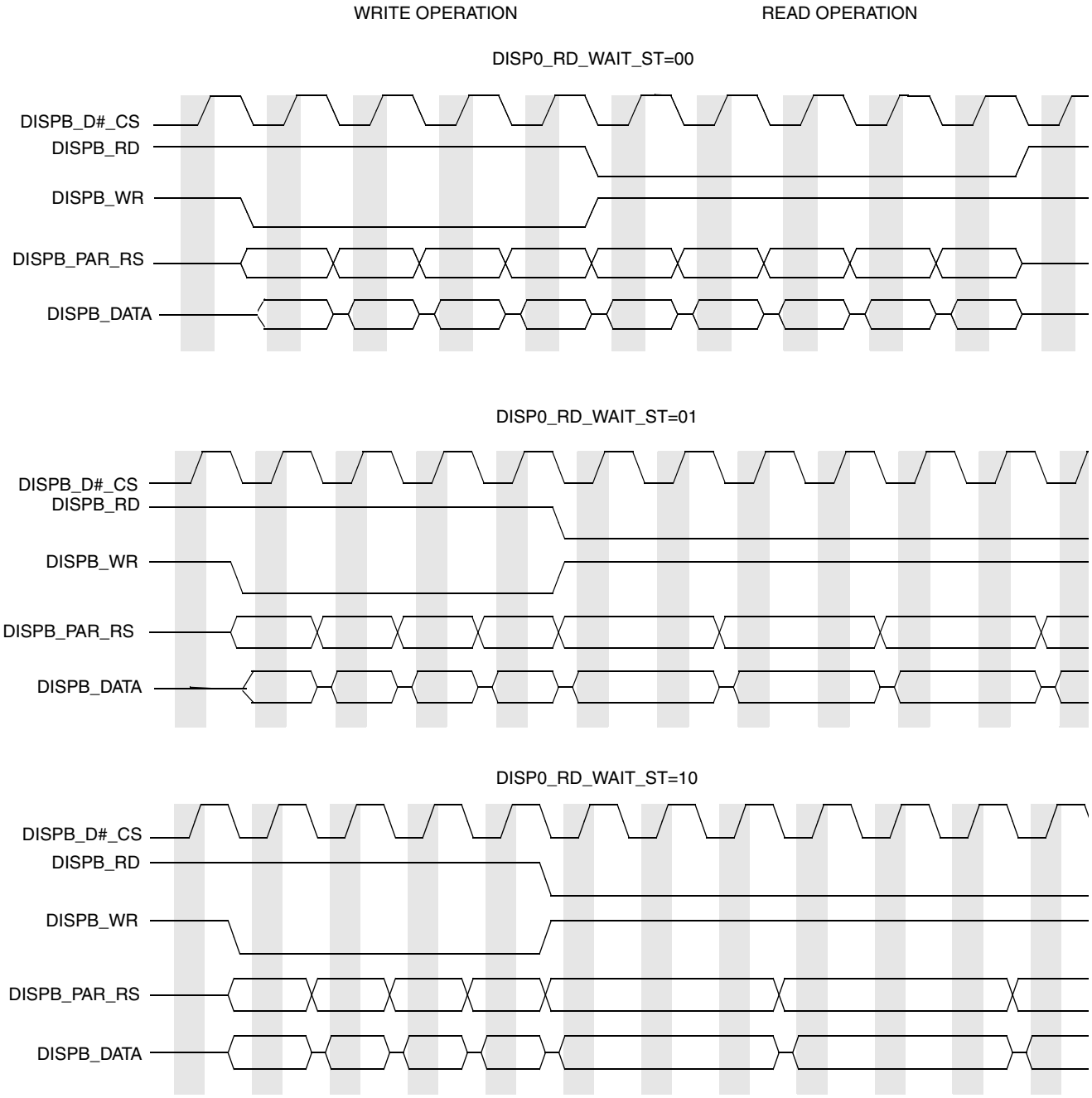


Figure 56. Parallel Interface Timing Diagram—Read Wait States

4.3.15.5.2 Parallel Interfaces, Electrical Characteristics

Figure 57, Figure 59, Figure 58, and Figure 60 depict timing of asynchronous parallel interfaces based on the system 80 and system 68k interfaces. Table 50 lists the timing parameters at display access level. All timing images are based on active low control signals (signals polarity is controlled via the DI_DISP_SIG_POL Register).

The interface is meant to be used with synchronous SIM cards. This means that the SIM module provides a clock for the SIM card to use. The frequency of this clock is normally 372 times the data rate on the TX/RX pins, however SIM module can work with CLK equal to 16 times the data rate on TX/RX pins.

There is no timing relationship between the clock and the data. The clock that the SIM module provides to the aim card will be used by the SIM card to recover the clock from the data much like a standard UART. All six (or 5 in case bi-directional TXRX is used) of the pins for each half of the SIM module are asynchronous to each other.

There are no required timing relationships between the signals in normal mode, but there are some in two specific cases: reset and power down sequences.

4.3.20.1 General Timing Requirements

Figure 73 shows the timing of the SIM module, and Figure 57 lists the timing parameters.

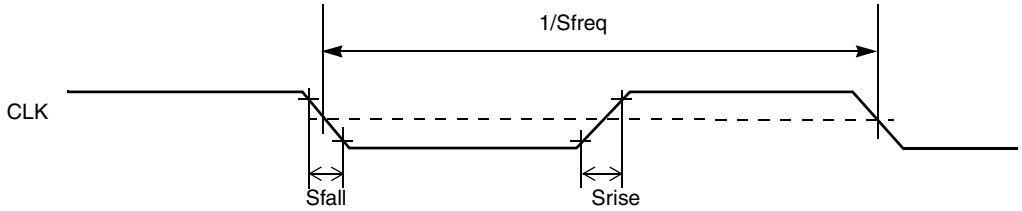


Figure 73. SIM Clock Timing Diagram

Table 57. SIM Timing Specification—High Drive Strength

Num	Description	Symbol	Min	Max	Unit
1	SIM Clock Frequency (CLK)[1]	S_{freq}	0.01	5 (Some new cards may reach 10)	MHz
2	SIM CLK Rise Time [2]	S_{rise}	—	20	ns
3	SIM CLK Fall Time [3]	S_{fall}	—	20	ns
4	SIM Input Transition Time (RX, SIMPD)	S_{trans}	—	25	ns

1 50% duty cycle clock
2 With C = 50pF
3 With C = 50pF

4.3.20.2 Reset Sequence

4.3.20.2.1 Cards with Internal Reset

The sequence of reset for this kind of SIM Cards is as follows (see Figure 74):

- After powerup, the clock signal is enabled on SGCLK (time T0)
- After 200 clock cycles, RX must be high.
- The card must send a response on RX acknowledging the reset between 400 and 40000 clock cycles after T0.

4.3.22.2 SSI Receiver Timing with Internal Clock

Figure 82 depicts the SSI receiver timing with internal clock, and Table 61 lists the timing parameters.

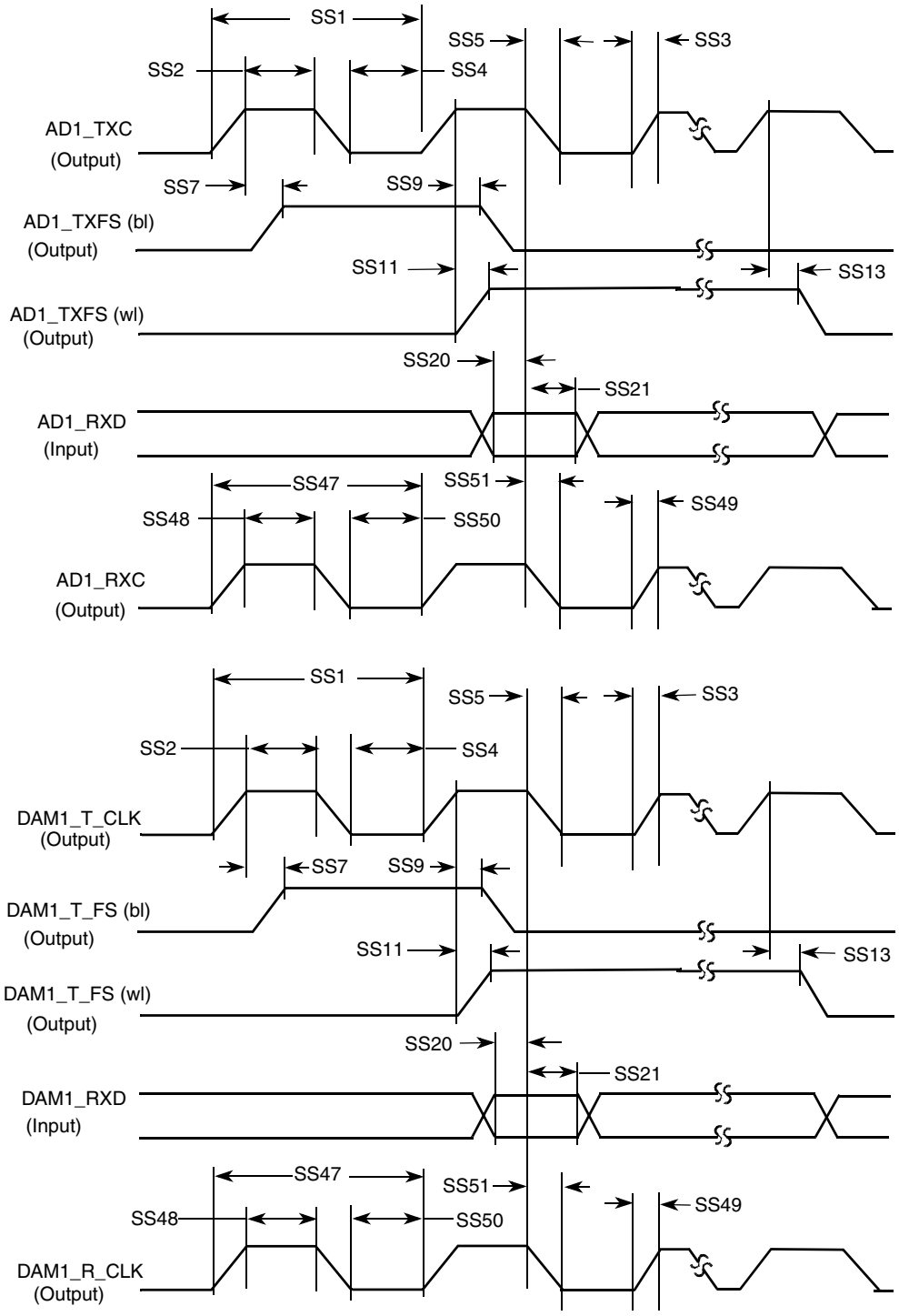


Figure 82. SSI Receiver with Internal Clock Timing Diagram

4.3.22.4 SSI Receiver Timing with External Clock

Figure 84 depicts the SSI receiver timing with external clock, and Table 63 lists the timing parameters.

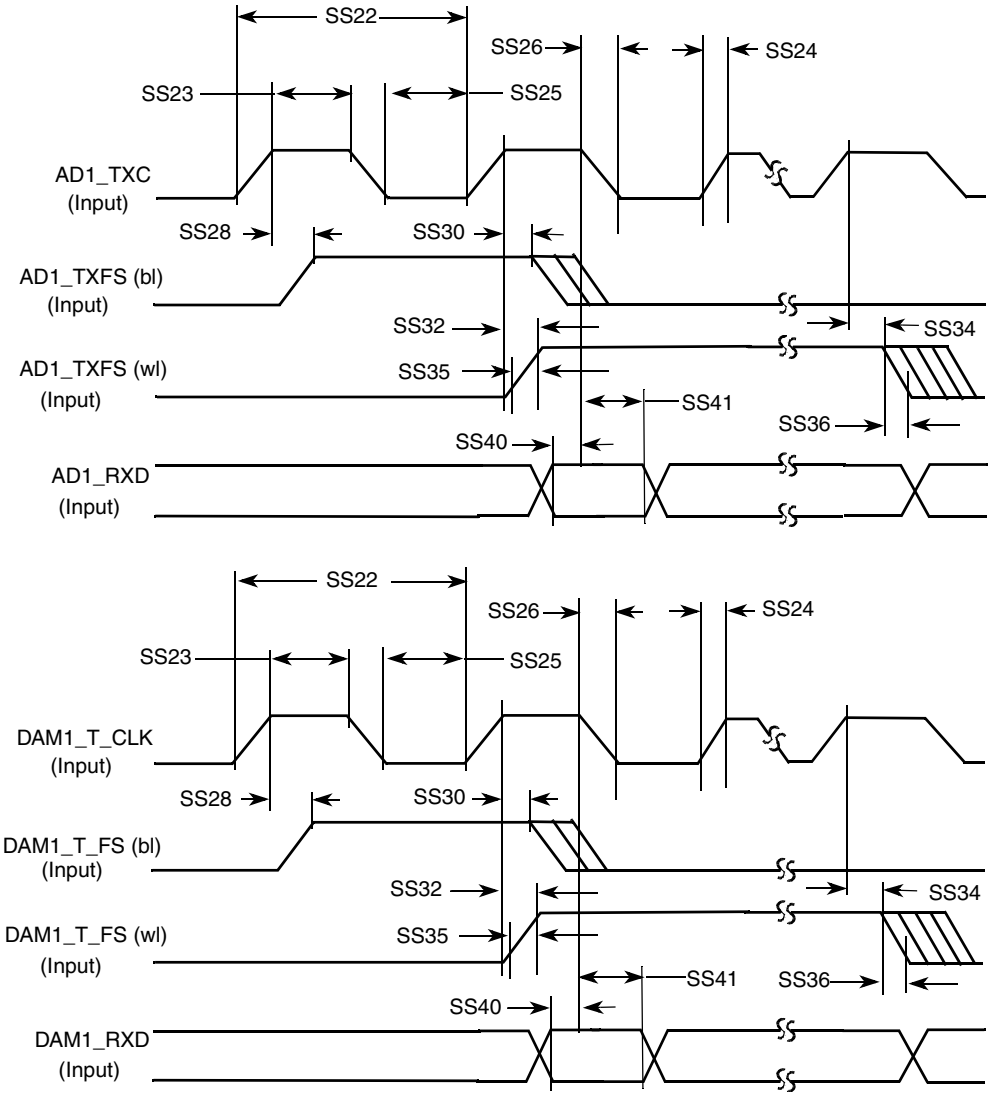


Figure 84. SSI Receiver with External Clock Timing Diagram

Table 63. SSI Receiver with External Clock Timing Parameters

ID	Parameter	Min	Max	Unit
External Clock Operation				
SS22	(Tx/Rx) CK clock period	81.4	—	ns
SS23	(Tx/Rx) CK clock high period	36.0	—	ns
SS24	(Tx/Rx) CK clock rise time	—	6.0	ns
SS25	(Tx/Rx) CK clock low period	36.0	—	ns
SS26	(Tx/Rx) CK clock fall time	—	6.0	ns

5 Package Information and Pinout

This section includes the contact assignment information and mechanical package drawing for the MCIMX31.

5.1 MAPBGA Production Package—457 14 x 14 mm, 0.5 mm Pitch

This section contains the outline drawing, signal assignment map (see Section 8, "Revision History," Table 70 for the 0.5 mm 14 × 14 MAPBGA signal assignments), and MAPBGA ground/power ID by ball grid location for the 457 14 x 14 mm, 0.5 mm pitch package.

5.1.1 Production Package Outline Drawing–14 x 14 mm 0.5 mm

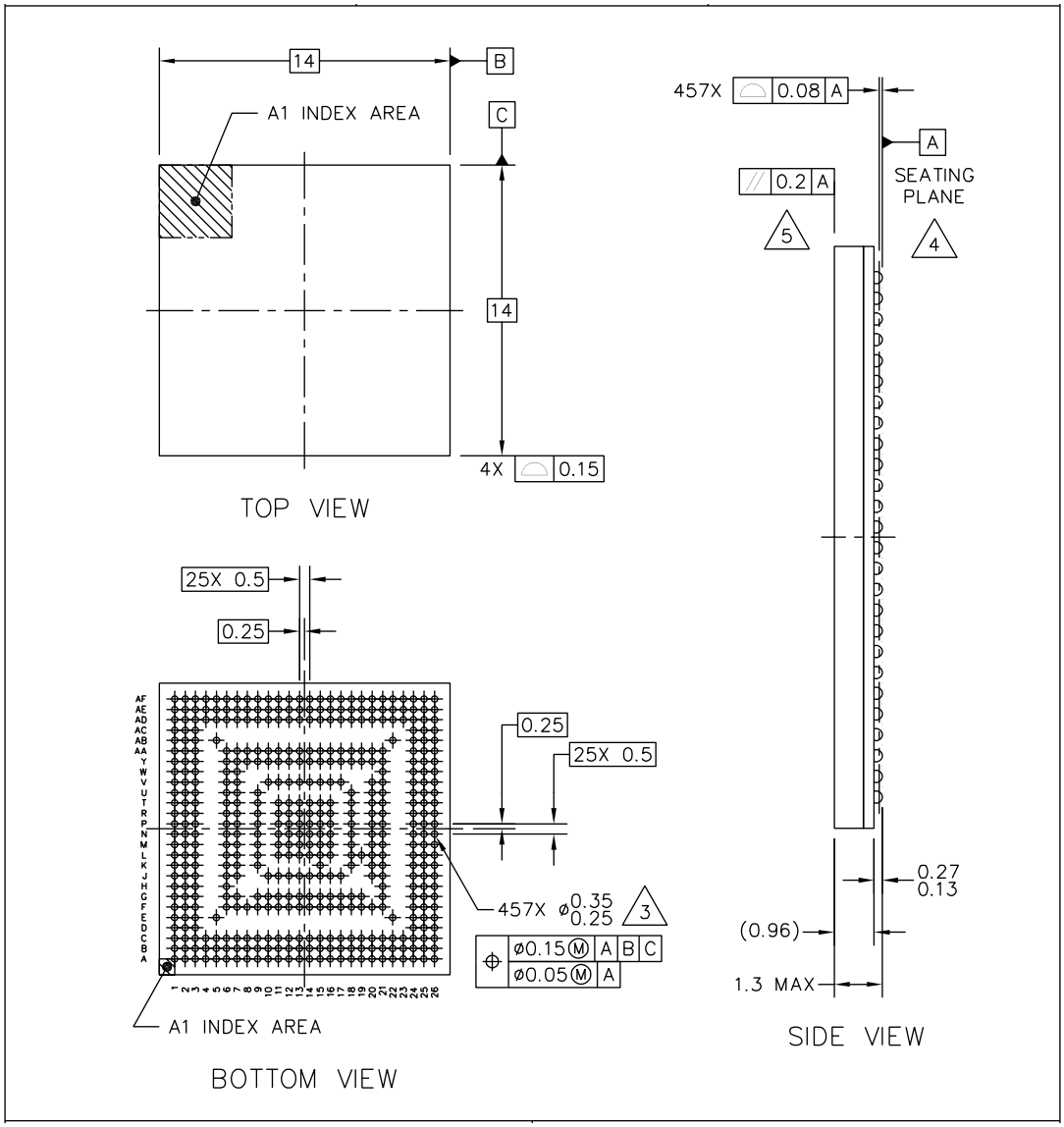


Figure 86. Production Package: Case 1581—0.5 mm Pitch